# **Complementary Power Transistors**

## **DPAK for Surface Mount Applications**

Designed for general purpose power and switching such as output or driver stages in applications such as switching regulators, converters, and power amplifiers.

### Features

- Lead Formed for Surface Mount Application in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Electrically Similar to Popular D44H/D45H Series
- Low Collector Emitter Saturation Voltage
- Fast Switching Speeds
- Complementary Pairs Simplifies Designs
- Epoxy Meets UL 94 V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

<b>MAXIMUM RATINGS</b> ( $T_A = 25^{\circ}C$ , a sign, "–", for PNP omitted, unless other			minus
Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	80	Vdc
Emitter-Base Voltage	V <sub>EB</sub>	5	Vdc
Collector Current – Continuous	۱ <sub>C</sub>	8	Adc
Collector Current – Peak	I <sub>CM</sub>	16	Adc
Total Power Dissipation @ $T_C = 25^{\circ}C$ Derate above $25^{\circ}C$	P <sub>D</sub>	20 0.16	W ₩/°C
Total Power Dissipation (Note 1) @ T <sub>A</sub> = 25°C Derate above 25°C	PD	1.75 0.014	W W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	С	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

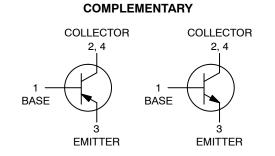
1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

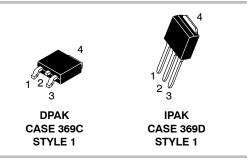


### **ON Semiconductor®**

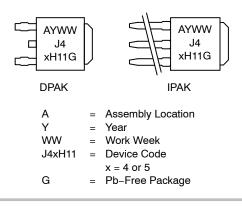
http://onsemi.com

### SILICON POWER TRANSISTORS 8 AMPERES 80 VOLTS, 20 WATTS





### MARKING DIAGRAMS



### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

#### THERMAL CHARACTERISTICS

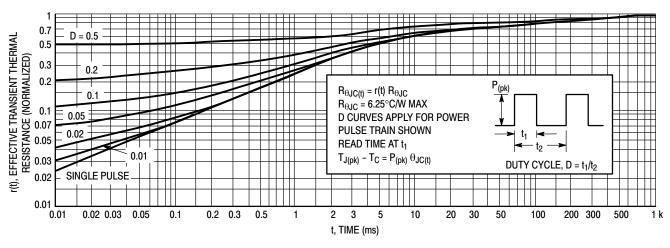
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	6.25	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	71.4	°C/W
Lead Temperature for Soldering	TL	260	°C

2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

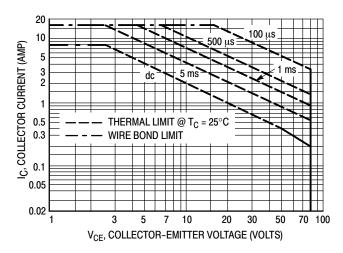
#### **ELECTRICAL CHARACTERISTICS**

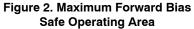
( $T_A = 25^{\circ}C$ , common for NPN and PNP, minus sign, "–", for PNP omitted, unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	<u>!</u> <b>!</b>		•	ł	•
Collector-Emitter Sustaining Voltage $(I_{C} = 30 \text{ mA}, I_{B} = 0)$	V <sub>CEO(sus)</sub>	80	_	-	Vdc
Collector Cutoff Current (V <sub>CE</sub> = Rated V <sub>CEO</sub> , V <sub>BE</sub> = 0)	I <sub>CES</sub>	_	_	1.0	μΑ
Emitter Cutoff Current (V <sub>EB</sub> = 5 Vdc)	I <sub>EBO</sub>	_	_	1.0	μΑ
ON CHARACTERISTICS			÷		•
Collector-Emitter Saturation Voltage $(I_{C} = 8 \text{ Adc}, I_{B} = 0.4 \text{ Adc})$	V <sub>CE(sat)</sub>	-	_	1	Vdc
Base-Emitter Saturation Voltage (I <sub>C</sub> = 8 Adc, I <sub>B</sub> = 0.8 Adc)	V <sub>BE(sat)</sub>	_	-	1.5	Vdc
DC Current Gain (V <sub>CE</sub> = 1 Vdc, I <sub>C</sub> = 2 Adc) (V <sub>CE</sub> = 1 Vdc, I <sub>C</sub> = 4 Adc)	h <sub>FE</sub>	60 40			_
DYNAMIC CHARACTERISTICS	· · · · · ·				
Collector Capacitance (V <sub>CB</sub> = 10 Vdc, f <sub>test</sub> = 1 Mhz) MJD44H11, NJVMJD44H11G/T4G/RLG MJD45H11, NJVMJD45H11G/T4G/RLG	C <sub>cb</sub>	-	45 130		pF
Gain Bandwidth Product (I <sub>C</sub> = 0.5 Adc, V <sub>CE</sub> = 10 Vdc, f = 20 Mhz) MJD44H11, NJVMJD44H11G/T4G/RLG MJD45H11, NJVMJD45H11G/T4G/RLG	fT	-	85 90		MHz
SWITCHING TIMES			•		•
Delay and Rise Times (I <sub>C</sub> = 5 Adc, I <sub>B1</sub> = 0.5 Adc) MJD44H11, NJVMJD44H11G/T4G/RLG MJD45H11, NJVMJD45H11G/T4G/RLG	t <sub>d</sub> + t <sub>r</sub>	-	300 135		ns
Storage Time (I <sub>C</sub> = 5 Adc, I <sub>B1</sub> = I <sub>B2</sub> = 0.5 Adc) MJD44H11, NJVMJD44H11G/T4G/RLG MJD45H11, NJVMJD45H11G/T4G/RLG	t <sub>s</sub>	-	500 500		ns
Fall Time (I <sub>C</sub> = 5 Adc, I <sub>B1</sub> = I <sub>B2</sub> = 0.5 Adc) MJD44H11, NJVMJD44H11G/T4G/RLG MJD45H11, NJVMJD45H11G/T4G/RLG	t <sub>f</sub>	-	140 100		ns



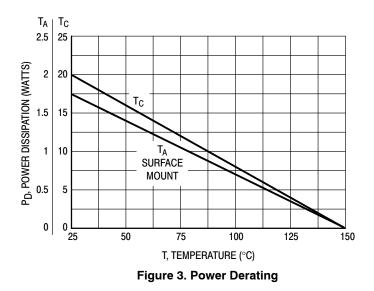
**Figure 1. Thermal Response** 

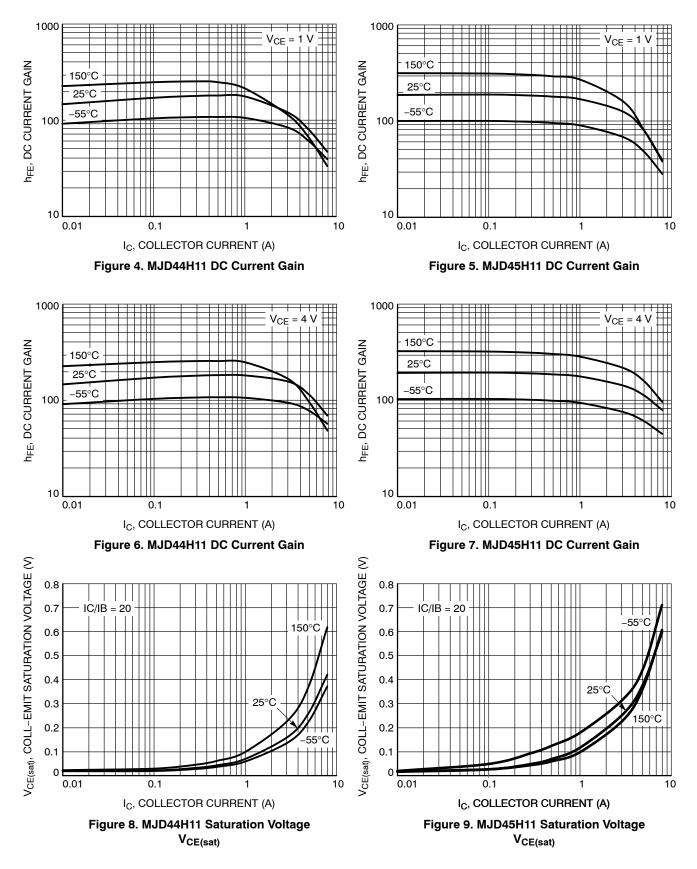


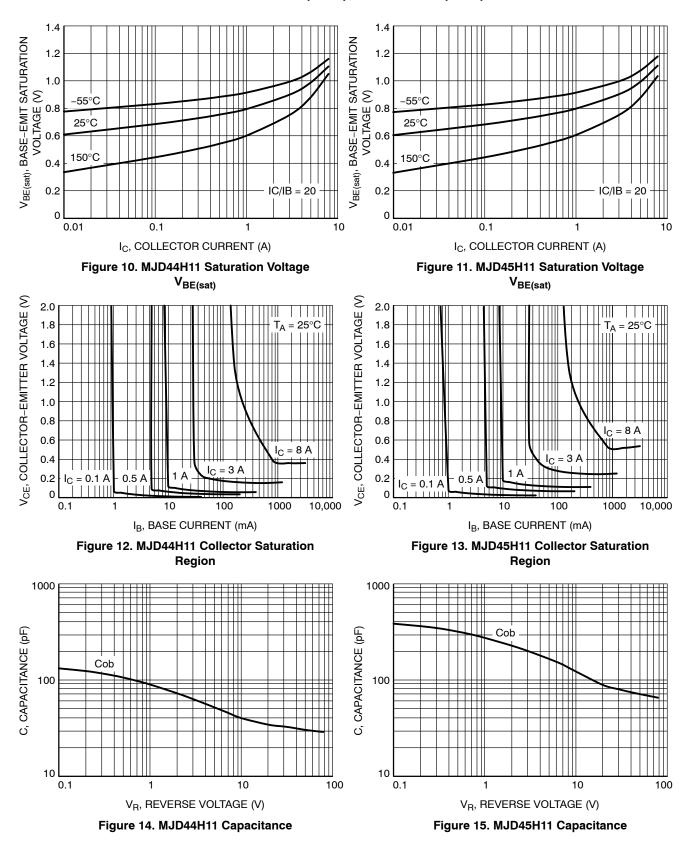


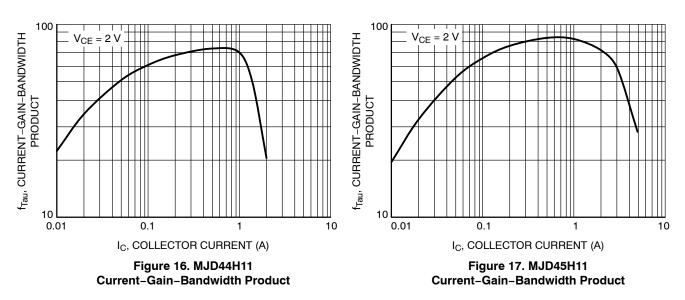
There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on  $T_{J(pk)} = 150^{\circ}$ C;  $T_{C}$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} \le 150^{\circ}$ C.  $T_{J(pk)}$  may be calculated from the data in Figure 1. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.









### ORDERING INFORMATION

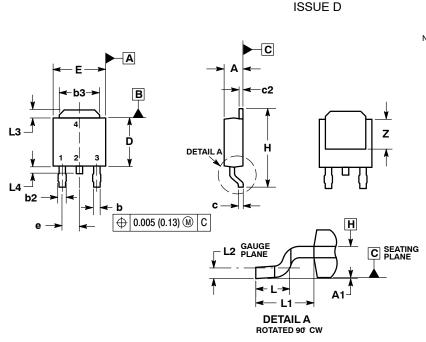
Device	Package Type	Package	Shipping <sup>†</sup>	
MJD44H11G	H11G DPAK (Pb-Free)		75 Units / Rail	
NJVMJD44H11G	JVMJD44H11G DPAK (Pb-Free)		75 Units / Rail	
MJD44H11-1G	4H11–1G DPAK–3 (Pb–Free)		75 Units / Rail	
MJD44H11RLG	D44H11RLG DPAK (Pb-Free)		1,800 / Tape & Reel	
NJVMJD44H11RLG*	NJVMJD44H11RLG* DPAK (Pb-Free)		1,800 / Tape & Reel	
MJD44H11T4G	JD44H11T4G DPAK (Pb-Free)		2,500 / Tape & Reel	
NJVMJD44H11T4G*	VMJD44H11T4G* DPAK (Pb-Free)		2,500 / Tape & Reel	
MJD44H11T5G	1T5G DPAK (Pb-Free)		2,500 / Tape & Reel	
/JD45H11G DPAK (Pb-Free)		369C	75 Units / Rail	
NJVMJD45H11G* DPAK (Pb-Free)		369C	75 Units / Rail	
MJD45H11-1G DPAK-3 (Pb-Free)		369D	75 Units / Rail	
JD45H11RLG DPAK (Pb-Free)		369C	1,800 / Tape & Reel	
NJVMJD45H11RLG*	IVMJD45H11RLG* DPAK (Pb-Free)		1,800 / Tape & Reel	
MJD45H11T4G	D45H11T4G DPAK (Pb-Free)		2,500 / Tape & Reel	
NJVMJD45H11T4G*	DPAK (Pb–Free)	369C	2,500 / Tape & Reel	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

### PACKAGE DIMENSIONS

DPAK CASE 369C



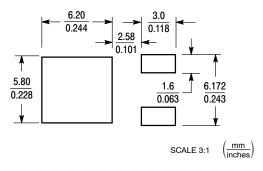
- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: INCHES.
  3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-MENSIONS b3, L3 and Z.
  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
  5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
  - OUTERMOST EXTREMES OF THE PLASTIC BODY. 6. DATUMS A AND B ARE DETERMINED AT DATUM
  - PLANE H.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.086	0.094	2.18	2.38	
A1	0.000	0.005	0.00	0.13	
b	0.025	0.035	0.63	0.89	
b2	0.030	0.045	0.76	1.14	
b3	0.180	0.215	4.57	5.46	
С	0.018	0.024	0.46	0.61	
c2	0.018	0.024	0.46	0.61	
D	0.235	0.245	5.97	6.22	
Е	0.250	0.265	6.35	6.73	
е	0.090	BSC	2.29 BSC		
Н	0.370	0.410	9.40	10.41	
L	0.055	0.070	1.40	1.78	
L1	0.108 REF		2.74	REF	
L2	0.020 BSC		0.51	0.51 BSC	
L3	0.035	0.050	0.89	1.27	
L4		0.040		1.01	
Ζ	0.155		3.93		

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER

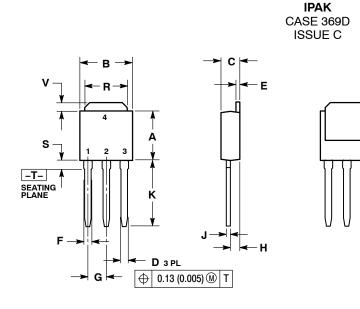
4. COLLECTOR

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS



NOTES

Ζ

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.245	5.97	6.35	
В	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
Е	0.018	0.023	0.46	0.58	
F	0.037	0.045	0.94	1.14	
G	0.090 BSC		2.29 BSC		
н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
Κ	0.350	0.380	8.89	9.65	
R	0.180	0.215	4.45	5.45	
S	0.025	0.040	0.63	1.01	
V	0.035	0.050	0.89	1.27	
Ζ	0.155		3.93		

STYLE 1: PIN 1. BASE

2. COLLECTOR 3. EMITTER

COLLECTOR

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